# High Voltage Switching Diode

The NSD350H is a high voltage switching diode in a SOD-323 surface mount package.

### Features

- Small Footprint Package, SOD-323
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- Pb-free Device, Halogen Free/BFR Free and are RoHS Compliant

### **Typical Applications**

- Flat Panel TVs
- Power Supply
- Industrial
- Wireless Handsets
- Automotive Modules

### MAXIMUM RATINGS Single Diode (T<sub>A</sub> = $25^{\circ}$ C)

Rating	Symbol	Max	Unit
Reverse Voltage	V <sub>R</sub>	350	V
Forward Current (DC)	١ <sub>F</sub>	200	mA
Non-Repetitive Peak Forward Current (Square Wave, $T_J = 25^{\circ}C$ prior to surge) $t = 10 \ \mu s$ $t = 100 \ \mu s$ $t = 1 \ ms$ $t = 10 \ ms$	I <sub>FSM</sub>	12 5 2 1.5	A

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub> (Note 1)	250 2	mW mW/°C
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub> (Note 1)	500	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

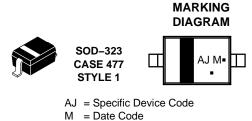
1. FR-4 100 mm<sup>2</sup> 2 oz Cu PCB



# **ON Semiconductor**<sup>®</sup>

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 <sup>=</sup> Pb–Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSD350HT1G	SOD-323	3000 / Tape &
NSVD350HT1G	(Pb-Free)	Reel

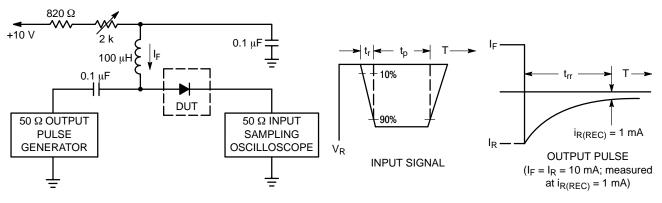
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NSD350H

### Table 1. ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage ( $I_R = 10 \ \mu A$ )	V <sub>(BR)R</sub>	350			V
Reverse Leakage (V <sub>R</sub> = 300 V)	۱ <sub>R</sub>			150	nA
Reverse Leakage (V <sub>R</sub> = 350 V)	I <sub>R</sub>			5	μΑ
Forward Voltage (I <sub>F</sub> = 100 mA)	V <sub>F</sub>			1.1	V
Total Capacitance ( $V_R = 0 V$ , f = 1.0 MHz)	CT			5.0	pF
Reverse Recovery Time ( $I_F = I_R = 10 \text{ mA}$ , $I_R(\text{rec}) = 1.0 \text{ mA}$ , Figure 1)	t <sub>rr</sub>		55		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (IF) of 10 mA.

2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 10 mA.

3. t<sub>p</sub> » t<sub>rr</sub>



## NSD350H

### **TYPICAL CHARACTERISTICS**

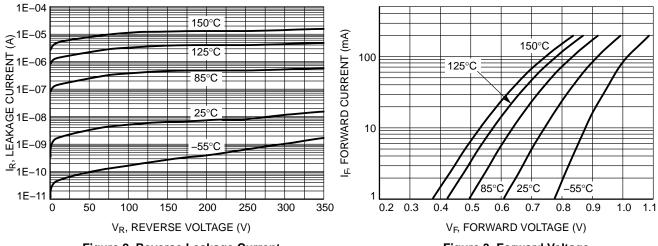




Figure 3. Forward Voltage

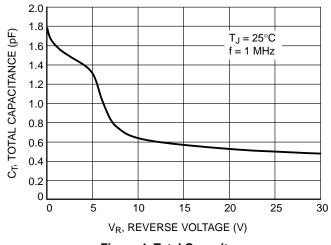
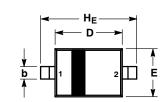


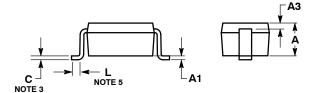
Figure 4. Total Capacitance



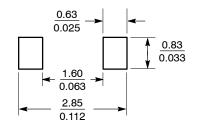








#### **SOLDERING FOOTPRINT\***



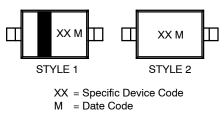
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 13 MAR 2007

- NOTES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETERS.
  LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
  DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF		0.006 REF			
b	0.25	0.32	0.4	0.010	0.012	0.016
С	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
Е	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105

#### GENERIC **MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present.

STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE STYLE 2: NO POLARITY

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SOD-323 CASE 477-02

**ISSUE H** 

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